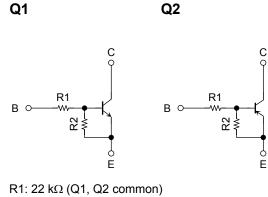
TOSHIBA Transistor Silicon NPN · PNP Epitaxial Type (PCT process) (Bias Resistor built-in Transistor)

# **RN47A2**

Switching, Inverter Circuit, Interface Circuit and Driver Circuit Applications.

- Two devices are incorporated into an Ultra-Super-Mini (5 pin) package.
- Incorporating a bias resistor into a transistor reduces parts count. Reducing the parts count enables the manufacture of ever more compact equipment and lowers assembly cost.

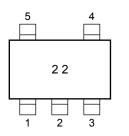
## **Equivalent Circuit and Bias Resistor Values**

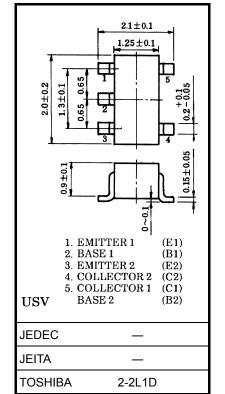


R2: 22 kΩ (Q1, Q2 common)

- Q1: RN1103F
- Q2: RN2103F

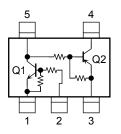
#### Marking





Weight:0.0062g (typ.)

## Equivalent Circuit (top view)



Unit: mm

## Absolute Maximum Ratings (Ta = 25°C) (Q1)

Characteristics	Symbol	Rating	Unit
Collector-base voltage	V <sub>CBO</sub>	50	V
Collector-emitter voltage	V <sub>CEO</sub>	50	V
Emitter-base voltage	V <sub>EBO</sub>	10	V
Collector current	Ι <sub>C</sub>	100	mA

## Absolute Maximum Ratings (Ta = 25°C) (Q2)

Characteristics	Symbol	Rating	Unit
Collector-base voltage	V <sub>CBO</sub>	-50	V
Collector-emitter voltage	V <sub>CEO</sub>	-50	V
Emitter-base voltage	V <sub>EBO</sub>	-10	V
Collector current	Ι <sub>C</sub>	-100	mA

#### Absolute Maximum Ratings (Ta = 25°C) (Q1, Q2 common)

Characteristics	Symbol	Rating	Unit
Collector power dissipation	P <sub>C</sub> (Note 1)	200	mW
Junction temperature	Tj	150	°C
Storage temperature range	T <sub>stg</sub>	-55~150	°C

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Note 1: Total rating

# Electrical Characteristics (Ta = 25°C) (Q1)

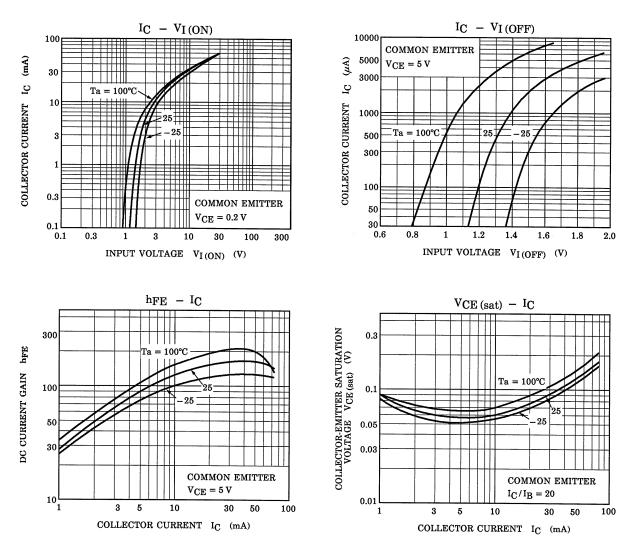
Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Collector cut-off current	I <sub>CBO</sub>	$V_{CB} = 50 \text{ V}, I_E = 0$			100	nA
	ICEO	$V_{CE}=50~V,~I_B=0$			500	117
Emitter cut-off current	I <sub>EBO</sub>	$V_{EB} = 10 \text{ V}, I_{C} = 0$	0.17		0.33	mA
DC current gain	h <sub>FE</sub>	$V_{CE} = 5 \text{ V}, \text{ I}_{C} = 10 \text{ mA}$	70	_		
Collector-emitter saturation voltage	V <sub>CE (sat)</sub>	I <sub>C</sub> = 5 mA, I <sub>B</sub> = 0.25 mA	_	0.1	0.3	V
Input voltage (ON)	V <sub>I (ON)</sub>	$V_{CE} = 0.2 \text{ V}, I_{C} = 5 \text{ mA}$	1.3	_	3.0	V
Input voltage (OFF)	VI (OFF)	$V_{CE} = 5 \text{ V}, \text{ I}_{C} = 0.1 \text{ mA}$	1.0	_	1.5	V
Transition frequency	f <sub>T</sub>	$V_{CE} = 10 \text{ V}, \text{ I}_{C} = 5 \text{ mA}$	_	250		MHz
Collector output capacitance	C <sub>ob</sub>	$V_{CB} = 10 \text{ V}, I_E = 0, f = 1 \text{ MHz}$		3		pF
Input resistor	R1	—	15.4	22	28.6	kΩ
Resistor ratio	R1/R2	—	0.8	1.0	1.2	

# Electrical Characteristics (Ta = 25°C) (Q2)

Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Collector cut-off current	I <sub>CBO</sub>	$V_{CB}=-50~V,~I_{E}=0$	_		-100	nA
	ICEO	$V_{CE} = -50 \text{ V}, \text{ I}_B = 0$	—	_	-500	
Emitter cut-off current	I <sub>EBO</sub>	$V_{EB} = -10 \text{ V}, I_C = 0$	-0.17	_	-0.33	mA
DC current gain	h <sub>FE</sub>	$V_{CE} = -5 \text{ V}, \text{ I}_{C} = -10 \text{ mA}$	70	_		
Collector-emitter saturation voltage	V <sub>CE (sat)</sub>	$I_C = -5 \text{ mA}, I_B = -0.25 \text{ mA}$	—	-0.1	-0.3	V
Input voltage (ON)	V <sub>I (ON)</sub>	$V_{CE}$ = -0.2 V, I <sub>C</sub> = -5 mA	-1.3	_	-3.0	V
Input voltage (OFF)	VI (OFF)	$V_{CE} = -5 \text{ V}, \text{ I}_{C} = -0.1 \text{ mA}$	-1.0	_	-1.5	V
Transition frequency	f <sub>T</sub>	$V_{CE} = -10 \text{ V}, \text{ I}_{C} = -5 \text{ mA}$	_	200		MHz
Collector output capacitance	C <sub>ob</sub>	$V_{CB} = -10 \text{ V}, I_E = 0, f = 1 \text{ MHz}$	_	3		pF
Input resistor	R1	—	15.4	22	28.6	kΩ
Resistor ratio	R1/R2	—	0.8	1.0	1.2	

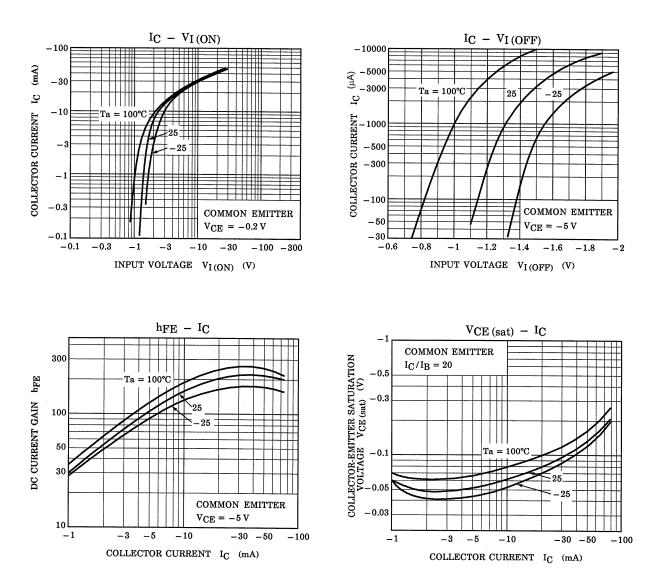
# **TOSHIBA**

Q1



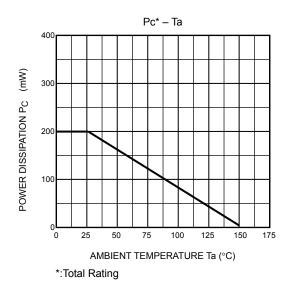
# <u>TOSHIBA</u>

Q2



# TOSHIBA

# Q1,Q2 Common



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20070701-EN GENERAL

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- TOSHIBA is continually working to improve the quality and reliability of its products. Nevertheless, semiconductor devices in general can malfunction or fail due to their inherent electrical sensitivity and vulnerability to physical stress. It is the responsibility of the buyer, when utilizing TOSHIBA products, to comply with the standards of safety in making a safe design for the entire system, and to avoid situations in which a malfunction or failure of such TOSHIBA products could cause loss of human life, bodily injury or damage to property.
   In developing your designs, please ensure that TOSHIBA products are used within specified operating ranges as set forth in the most recent TOSHIBA products specifications. Also, please keep in mind the precautions and conditions set forth in the "Handling Guide for Semiconductor Devices," or "TOSHIBA Semiconductor Reliability Handbook" etc.
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